

30V N-Channel NexFET™ Power MOSFET

FEATURES

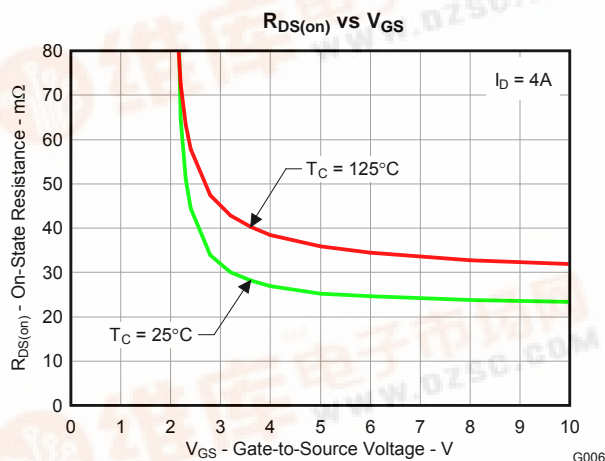
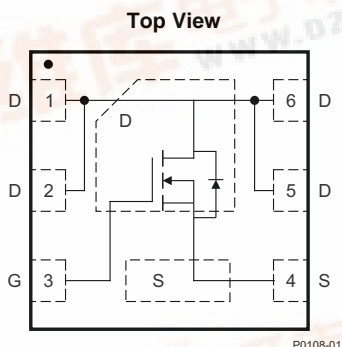
- Optimized for 5V Gate Drive
- Ultra Low Q_g and Q_{gd}
- Low Thermal Resistance
- Pb Free
- RoHS Compliant
- Halogen Free
- SON 2-mm × 2-mm Plastic Package

APPLICATIONS

- DC-DC Converters
- Battery and Load Management Applications

DESCRIPTION

The NexFET power MOSFET has been designed to minimize losses in power conversion applications and optimized for 5V gate drive applications. The 2-mm × 2-mm SON offers excellent thermal performance for the size of the package.



PRODUCT SUMMARY

V_{DS}	Drain to Source Voltage	30	V
Q_g	Gate Charge Total (4.5V)	2.1	nC
Q_{gd}	Gate Charge Gate to Drain	0.4	nC
$R_{DS(on)}$	Drain to Source On Resistance	$V_{GS} = 3V$	31 mΩ
		$V_{GS} = 4.5V$	26 mΩ
		$V_{GS} = 8V$	24 mΩ
$V_{GS(th)}$	Threshold Voltage	1.3	V

ORDERING INFORMATION

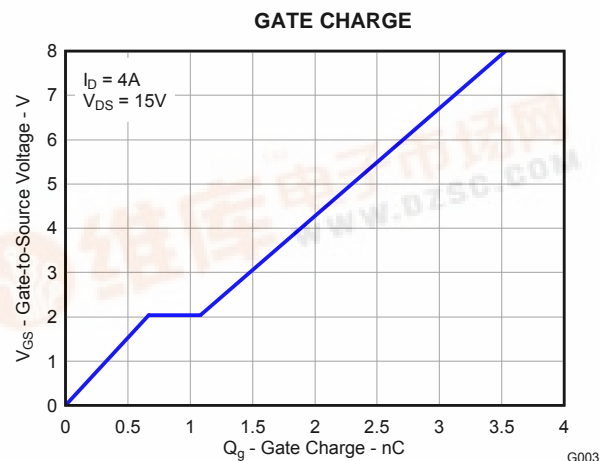
Device	Package	Media	Qty	Ship
CSD17313Q2	SON 2-mm × 2-mm Plastic Package	13-Inch Reel	3000	Tape and Reel

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ unless otherwise stated		VALUE	UNIT
V_{DS}	Drain to Source Voltage	30	V
V_{GS}	Gate to Source Voltage	+10 / -8	V
I_D	Continuous Drain Current, $T_C = 25^\circ\text{C}$	5	A
	Continuous Drain Current ⁽¹⁾	5	A
I_{DM}	Pulsed Drain Current, $T_A = 25^\circ\text{C}$ ⁽²⁾	20	A
P_D	Power Dissipation	2.3	W
T_J , T_{STG}	Operating Junction and Storage Temperature Range	-55 to 150	$^\circ\text{C}$
E_{AS}	Avalanche Energy, Single Pulse, $I_D = 19A$, $L = 0.1mH$, $R_G = 25\Omega$	18	mJ

(1) Package Limited

(2) Pulse duration $\leq 300\mu s$, duty cycle $\leq 2\%$



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

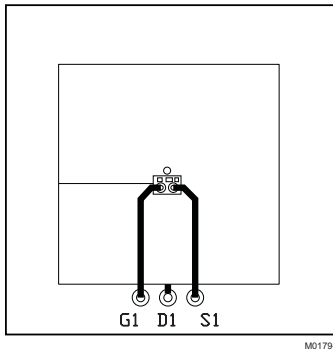
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Characteristics						
B _V D _{SS}	Drain to Source Voltage	V _{GS} = 0V, I _D = 250μA	30			V
I _{DSS}	Drain to Source Leakage	V _{GS} = 0V, V _{DS} = 24V			1	μA
I _{GSS}	Gate to Source Leakage	V _{DS} = 0V, V _{GS} = +10 / -8V			100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	V _{DS} = V _{GS} , I _D = 250μA	0.9	1.3	1.8	V
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 3V, I _D = 4A		31	42	mΩ
		V _{GS} = 4.5V, I _D = 4A		26	32	mΩ
		V _{GS} = 8V, I _D = 4A		24	30	mΩ
g _{fs}	Transconductance	V _{DS} = 15V, I _D = 4A		16		S
Dynamic Characteristics						
C _{iss}	Input Capacitance	V _{GS} = 0V, V _{DS} = 15V, f = 1MHz		260	340	pF
C _{oss}	Output Capacitance			140	180	pF
C _{rss}	Reverse Transfer Capacitance			13	17	pF
R _G	Series Gate Resistance			1.3	2.6	Ω
Q _g	Gate Charge Total (4.5V)	V _{DS} = 15V, I _D = 4A		2.1	2.7	nC
Q _{gd}	Gate Charge – Gate to Drain			0.4		nC
Q _{gs}	Gate Charge Gate to Source			0.7		nC
Q _{g(th)}	Gate Charge at V _{th}			0.3		nC
Q _{oss}	Output Charge	V _{DS} = 13.5V, V _{GS} = 0V		3.8		nC
t _{d(on)}	Turn On Delay Time	V _{DS} = 15V, V _{GS} = 4.5V, I _D = 4A, R _G = 2Ω		2.8		ns
t _r	Rise Time			3.9		ns
t _{d(off)}	Turn Off Delay Time			4.2		ns
t _f	Fall Time			1.3		ns
Diode Characteristics						
V _{SD}	Diode Forward Voltage	I _{SD} = 4A, V _{GS} = 0V		0.85	1	V
Q _{rr}	Reverse Recovery Charge	V _{DD} = 13.5V, I _F = 4A, di/dt = 300A/μs		6.4		nC
t _{rr}	Reverse Recovery Time			12.9		ns

THERMAL CHARACTERISTICS

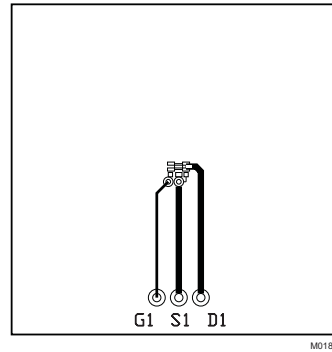
(T_A = 25°C unless otherwise stated)

PARAMETER		MIN	TYP	MAX	UNIT
R _{θJC}	Thermal Resistance Junction to Case ⁽¹⁾			7.4	°C/W
R _{θJA}	Thermal Resistance Junction to Ambient ⁽¹⁾⁽²⁾			67	°C/W

- (1) R_{θJC} is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch × 1.5-inch (3.81-cm × 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. R_{θJC} is specified by design, whereas R_{θJA} is determined by the user's board design.
- (2) Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.



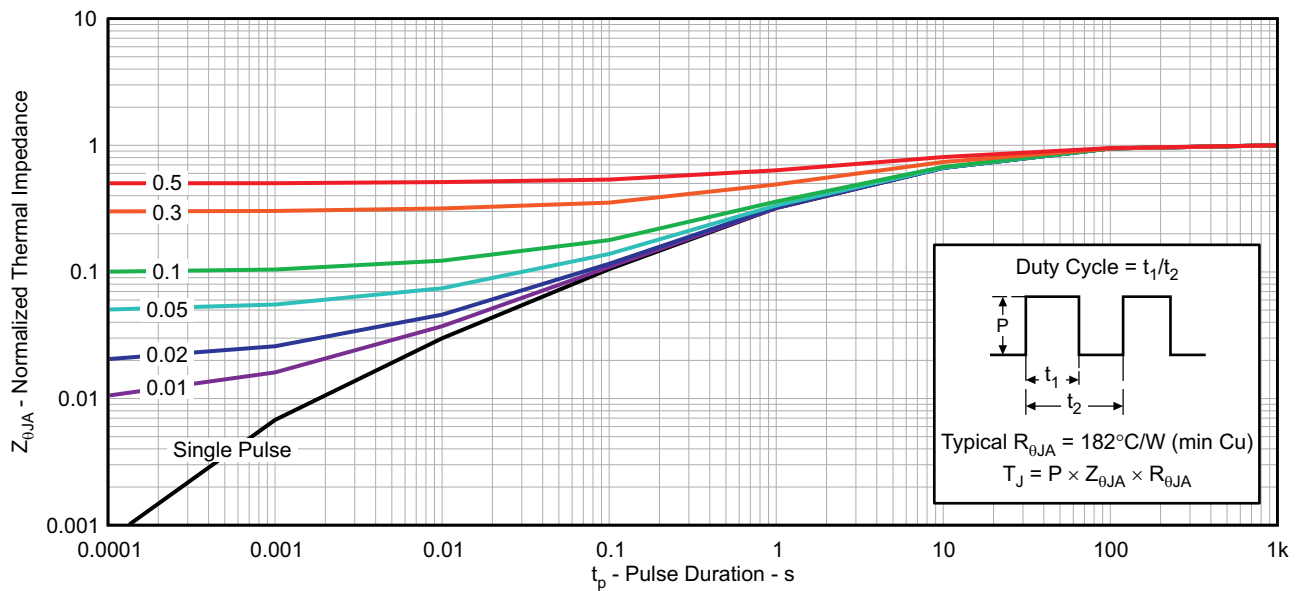
Max $R_{\theta JA} = 67^{\circ}\text{C/W}$
when mounted on
1 inch² (6.45 cm²) of
2-oz. (0.071-mm thick)
Cu.



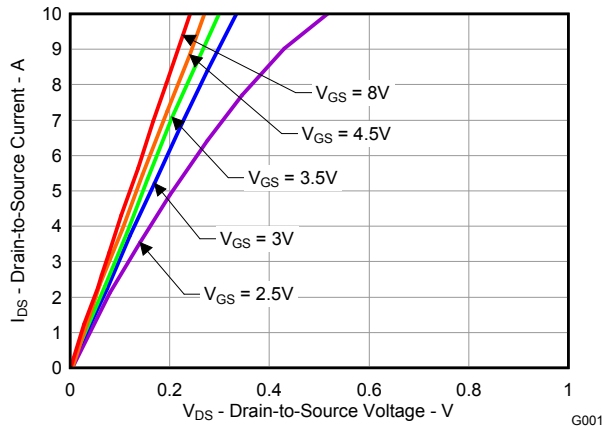
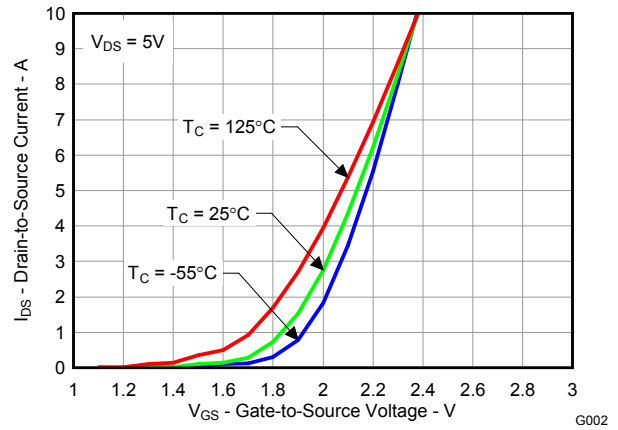
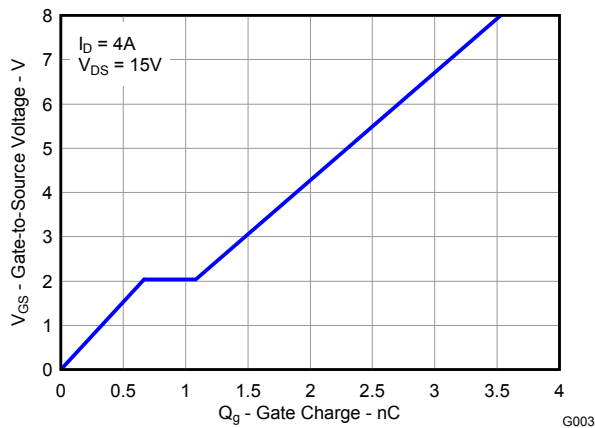
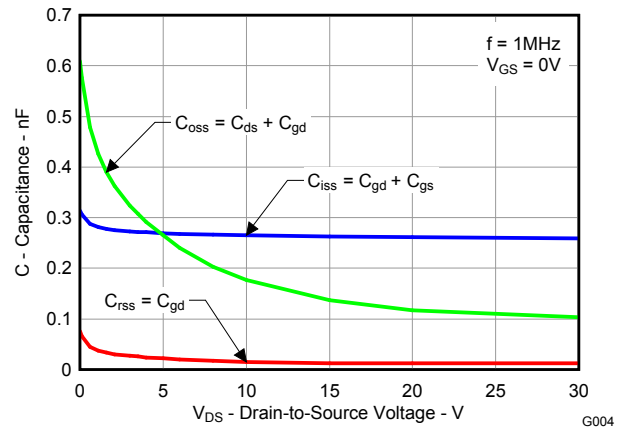
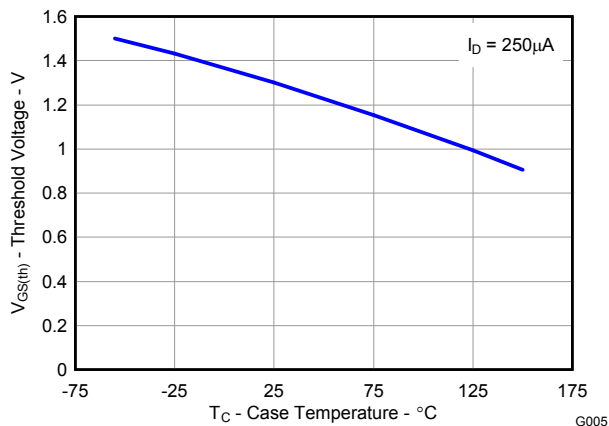
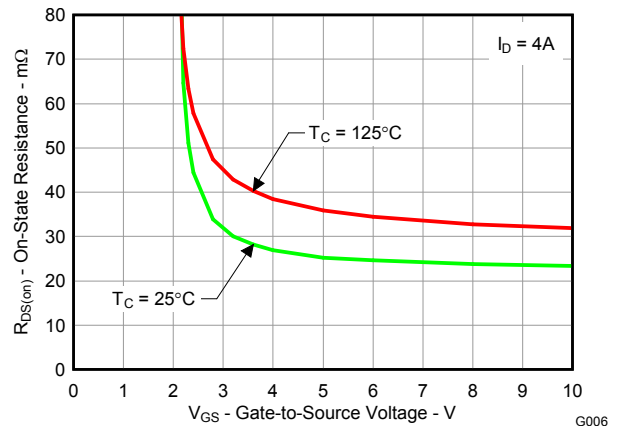
Max $R_{\theta JA} = 228^{\circ}\text{C/W}$
when mounted on a
minimum pad area of
2-oz. (0.071-mm thick)
Cu.

TYPICAL MOSFET CHARACTERISTICS

($T_A = 25^{\circ}\text{C}$ unless otherwise stated)



G012

TYPICAL MOSFET CHARACTERISTICS (continued)(T_A = 25°C unless otherwise stated)**Figure 2. Saturation Characteristics****Figure 3. Transfer Characteristics****Figure 4. Gate Charge****Figure 5. Capacitance****Figure 6. Threshold Voltage vs. Temperature****Figure 7. On-State Resistance vs. Gate-to-Source Voltage**

TYPICAL MOSFET CHARACTERISTICS (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

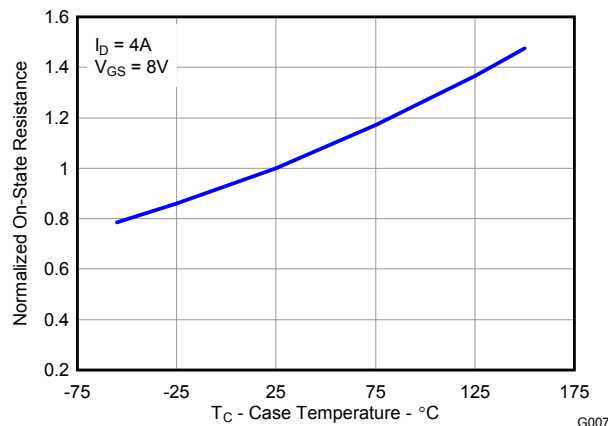


Figure 8. Normalized On-State Resistance vs. Temperature

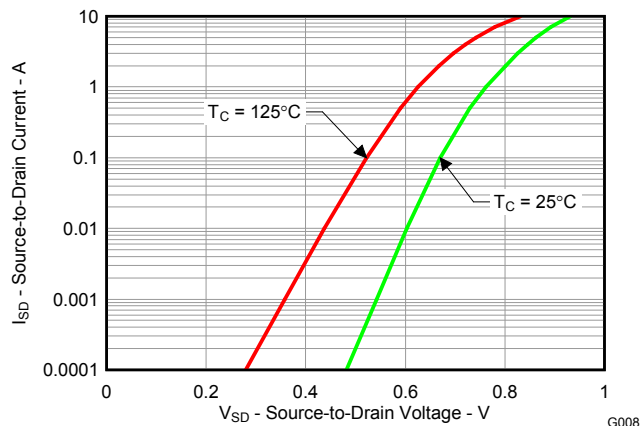


Figure 9. Typical Diode Forward Voltage

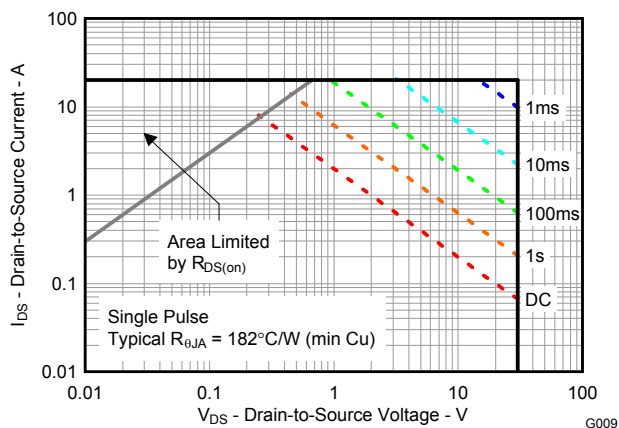


Figure 10. Maximum Safe Operating Area

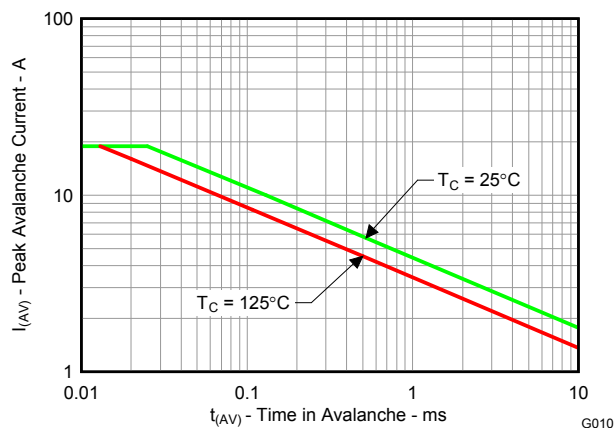


Figure 11. Single Pulse Unclamped Inductive Switching

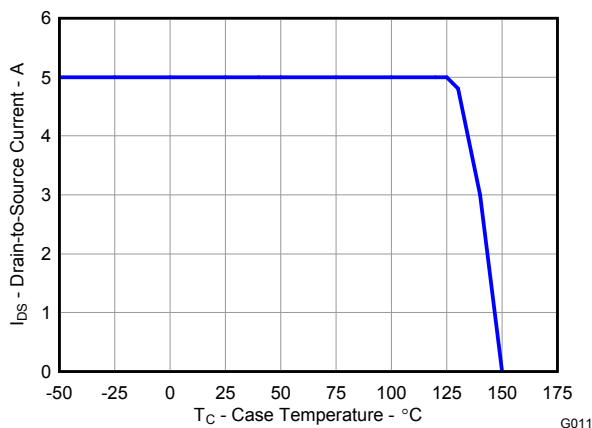
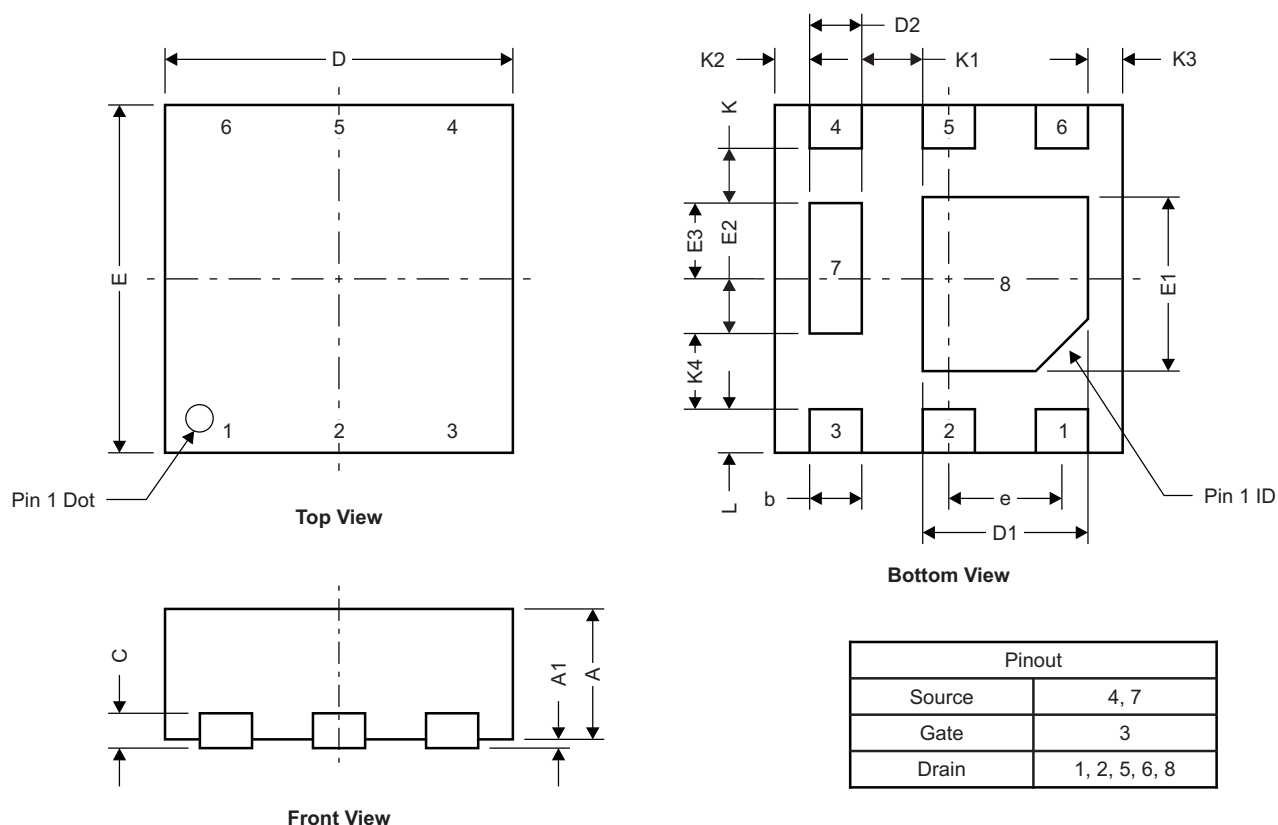


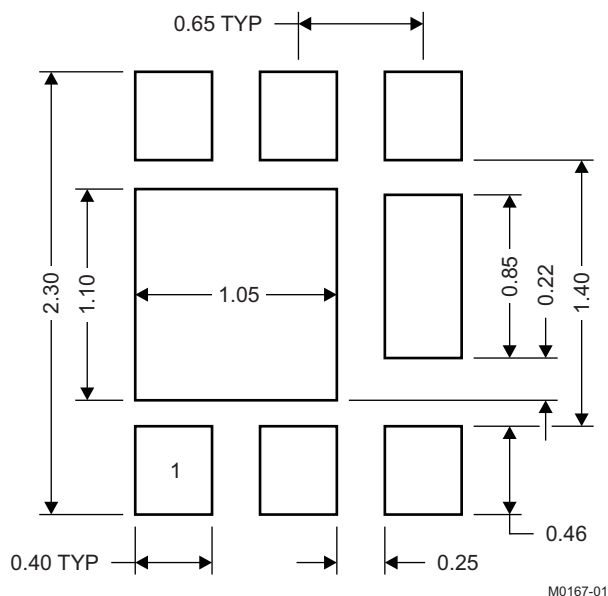
Figure 12. Maximum Drain Current vs. Temperature

MECHANICAL DATA**Q2 Package Dimensions**

M0175-02

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.700	0.750	0.800	0.028	0.030	0.032
A1	0.000		0.050	0.000		0.002
b	0.250	0.300	0.350	0.010	0.012	0.014
C	0.203 TYP			0.008 TYP		
D	2.000 TYP			0.080 TYP		
D1	0.900	0.950	1.000	0.036	0.038	0.040
D2	0.300 TYP			0.012 TYP		
E	2.000 TYP			0.080 TYP		
E1	0.900	1.000	1.100	0.036	0.040	0.044
E2	0.280 TYP			0.0112 TYP		
E3	0.470 TYP			0.0188 TYP		
e	0.650 BSC			0.026 TYP		
K	0.280 TYP			0.0112 TYP		
K1	0.350 TYP			0.014 TYP		
K2	0.200 TYP			0.008 TYP		
K3	0.200 TYP			0.008 TYP		
K4	0.470 TYP			0.0188 TYP		
L	0.200	0.25	0.300	0.008	0.010	0.012

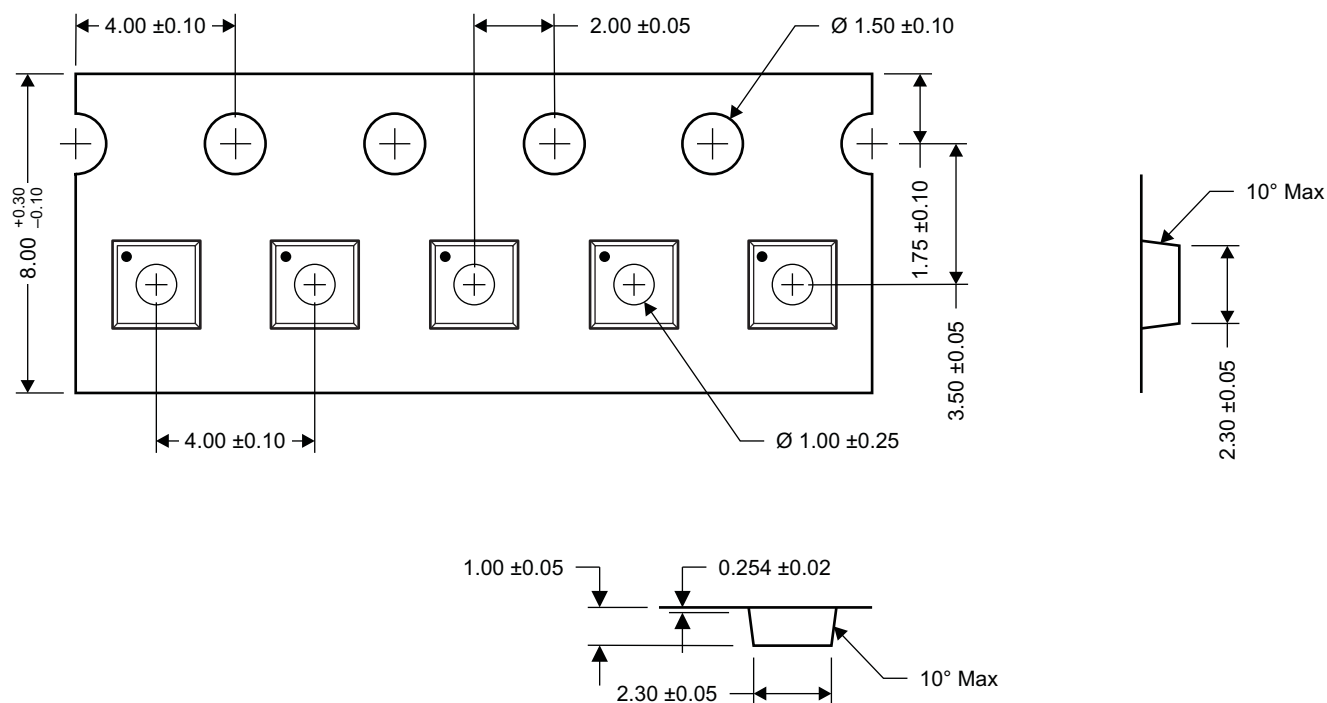
Recommended PCB Pattern



Note: All dimensions are in mm, unless otherwise specified.

For recommended circuit layout for PCB designs, see application note [SLPA005 – Reducing Ringing through PCB Layout Techniques](#).

Q2 Tape and Reel Information



- Notes:
1. Measured from centerline of sprocket hole to centerline of pocket
 2. Cumulative tolerance of 10 sprocket holes is ±0.20
 3. Other material available
 4. Typical SR of form tape Max 10^8 OHM/SQ
 5. All dimensions are in mm, unless otherwise specified.

[查询 CSD17313Q2 供应商](#)

REVISION HISTORY

Changes from Original (March 2010) to Revision A	Page
<ul style="list-style-type: none">Changed Q_{rr} - Reverse Recovery Charge From: 10.2 nC To: 6.4 nC	2
Changes from Revision A (March 2010) to Revision B	Page
<ul style="list-style-type: none">Deleted the Package Marking Information section	8



PACKAG

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Pea
CSD17313Q2	ACTIVE	SON	DQK	6	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-2600

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com> for more information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all RoHS compliant products except that lead may not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in high temperature applications.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die attach between the package and the carrier.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (RoHS). All processing materials must be Halogen and Antimony free (RoHS) to ensure this component meets RoHS requirements.

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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